TOSHIBA Field Effect Transistor Silicon P-Channel MOS Type (U-MOS IV)

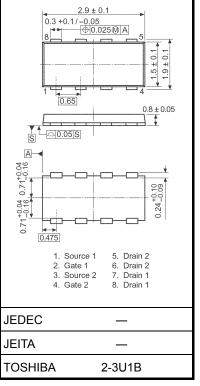
TPCF8304

Notebook PC Applications Portable Equipment Applications

- Low drain-source ON resistance: R_{DS (ON)} = 60 mΩ (typ.)
- High forward transfer admittance: |Y_{fs}| = 5.9 S (typ.)
- Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -30 \ V)$
- Enhancement model: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_D = -1 mA)

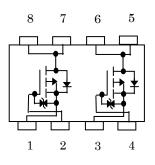
Cha	Symbol	Rating	Unit		
Drain-source voltage	n-source voltage VD			V	
Drain-gate voltage	(R _{GS} = 20 kΩ)	V _{DGR}	-30	V	
Gate-source voltag	je	V _{GSS}	±20	V	
Drain current	DC (Note 1)	ID	-3.2	А	
Diamounent	Pulse (Note 1)	I _{DP}	-30 -30 ±20	A	
Drain power dissipation (t = 5 s) (Note 2a)	Single-device operation (Note 3a)	P _{D (1)}	1.35	w	
	Single-device value at dual operation (Note 3b)	P _{D (2)}	1.12		
Drain power dissipation (t = 5 s) (Note 2b)	Single-device operation (Note 3a)	P _{D (1)}	0.53	vv	
	Single-device value at dual operation (Note 3b)	P _{D (2)}	0.33		
Single-pulse avala	nche energy (Note 4)	E _{AS}	0.67	mJ	
Avalanche current		I _{AR}	-1.6	А	
Repetitive avalanc Single-device value	E _{AR}	E _{AR} 0.11			
Channel temperatu	ıre	T _{ch}	150	°C	
Storage temperatu	T _{stg}	-55~150	°C		

Absolute Maximum Ratings (Ta = 25°C)



Weight: 0.011 g (typ.)

Circuit Configuration



Note: For Notes 1 to 5, see the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

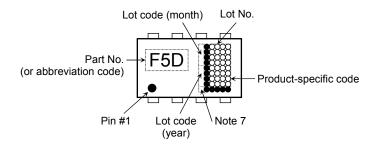
Caution: This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm

Thermal Characteristics

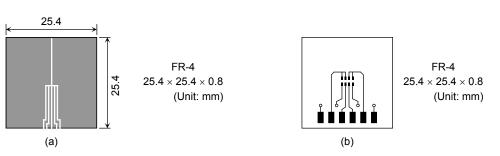
Chara	Symbol	Max	Unit		
Thermal resistance, channel to ambient (t = 5 s) (Note 2a)	Single-device operation (Note 3a)	R _{th (ch-a) (1)}	92.6	°C/W	
	Single-device value at dual operation (Note 3b)	R _{th (ch-a) (2)}	111.6	0,11	
Thermal resistance, channel to ambient	Single-device operation (Note 3a)	R _{th (ch-a) (1)}	235.8	- °C/W	
(t = 5 s) (Note 2b)	Single-device value at dual operation (Note 3b)	R _{th (ch-a) (2)}	378.8		

Marking (Note 6)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)



(b) Device mounted on a glass-epoxy board (b)

- Note 3: a) The power dissipation and thermal resistance values shown are for a single device. (During single-device operation, power is applied to one device only.)
 - b) The power dissipation and thermal resistance values shown are for a single device. (During dual operation, power is evenly applied to both devices.)

Note 4: $V_{DD} = -24 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$ (initial), L = 0.2 mH, R_G = 25 Ω , I_{AR} = -1.6 A

- Note 5: Repetitive rating; pulse width limited by max channel s temperature
- Note 6: to the lower left of the Part No. indicates Pin 1.
- Note 7: A dot marking identifies the indication of product Labels. Without a dot: [[Pb]]/INCLUDES > MCV With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

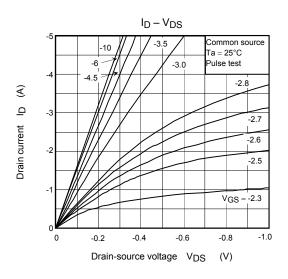
Electrical Characteristics (Ta = 25°C)

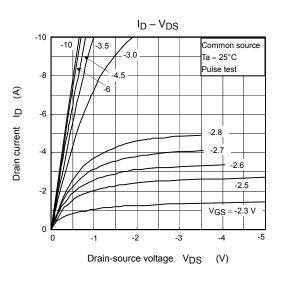
Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS}=\pm 16~V,~V_{DS}=0~V$	—	—	±10	μA
Drain cut-off curr	ent	I _{DSS}	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	— — -1 ¹		-10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-30	_	—	v
Drain-source bre			$I_D = -10 \text{ mA}, V_{GS} = 20 \text{ V}$	-15	-	—	
Gate threshold ve	oltage	V _{th}	$V_{DS} = -10 V, I_D = -1 mA$	-0.5	-	-1.2	V
Drain-source ON resistance		R _{DS (ON)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -1.6 \text{ A}$	—	80	105	mΩ
Drain-source ON	resistance	R _{DS (ON)}	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -1.6 \text{ A}$	—	60	72	1115.2
Forward transfer admittance		Y _{fs}	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1.6 \text{ A}$	2.9	5.9	—	S
Input capacitance		C _{iss}	V_{DS} = -10 V, V_{GS} = 0 V, f = 1 MHz	_	600	—	pF
Reverse transfer capacitance		C _{rss}		_	60	_	
Output capacitance		C _{oss}		_	70	_	
Switching time	Rise time	tr	$V_{GS} = -1.6 \text{ A}$ -10 V G = -1.6 A G = -1.6 A	_	5.3	_	
	Turn-on time	t _{on}		_	12	_	• ns
	Fall time	t _f		_	8.4	_	
	Turn-off time	t _{off}	$V_{DD}\simeq -15~V \label{eq:VDD}$ Duty \leq 1%, $t_W=10~\mu s$	_	34	_	
Total gate charge (gate-source plus gate-drain)		Qg	V _{DD} ≃ -24 V, V _{GS} = -10 V,	_	14	_	
Gate-source charge 1		Q _{gs1}	$I_{\rm D} = -3.2 \rm{A}$	—	1.4	—	nC
Gate-drain ("Miller") charge		Q _{gd}		_	2.7	—	

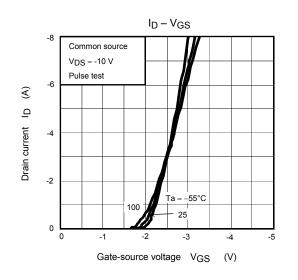
Source-Drain Ratings and Characteristics (Ta = 25°C)

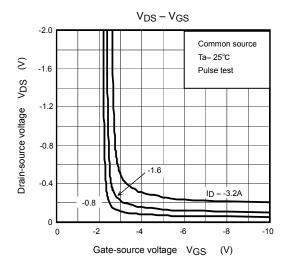
Characterist	tic	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)	I _{DRP}	—	_	_	-12.8	А
Forward voltage (diode)		V _{DSF}	$I_{DR} = -3.2 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$		_	1.2	V

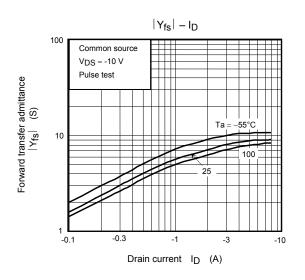
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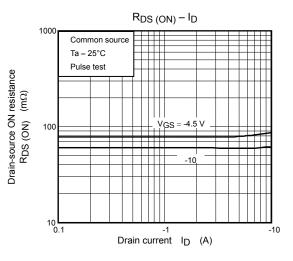




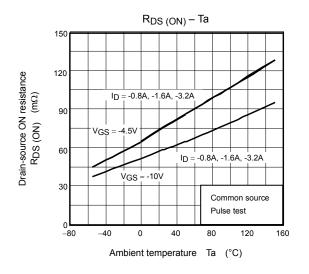


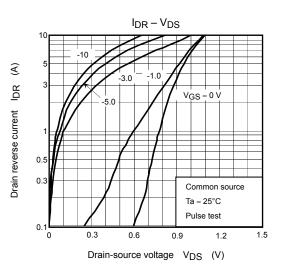


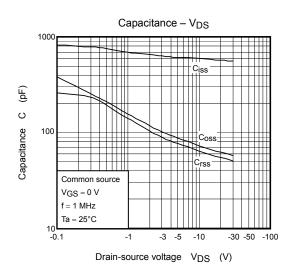


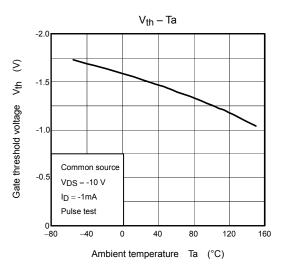


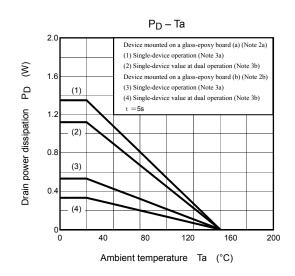
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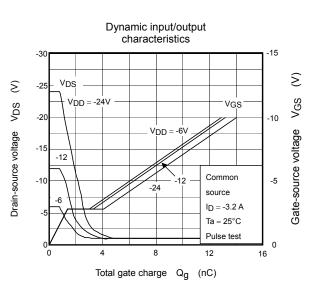


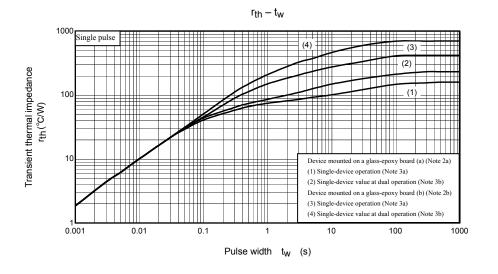


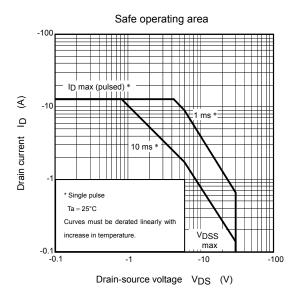












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